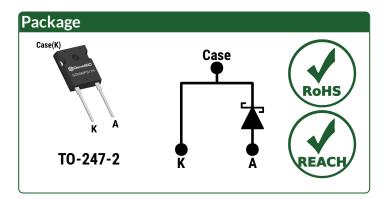
### Silicon Carbide Schottky Diode



 $V_{RRM}$  = 1700 V  $I_{F(T_C = 164^{\circ}C)}$  = 5 A  $Q_C$  = 41 nC

#### **Features**

- Gen4 Thin Chip Technology for Low V<sub>F</sub>
- Enhanced Surge and Avalanche Robustness
- Superior Figure of Merit Qc/IF
- Low Thermal Resistance
- Low Reverse Leakage Current
- Temperature Independent Fast Switching
- Positive Temperature Coefficient of V<sub>F</sub>
- Low V<sub>F</sub> for High Temperature Operation



### **Advantages**

- Improved System Efficiency
- High System Reliability
- Optimal Price Performance
- Reduced Cooling Requirements
- Increased System Power Density
- Zero Reverse Recovery Current
- Easy to Parallel without Thermal Runaway
- Improved System Efficiency

#### **Applications**

- EV Fast Chargers
- Solar Inverters
- Anti-Parallel / Free-Wheeling Diode
- Motor Drives
- High Frequency Rectifiers
- Switched Mode Power Supply (SMPS)
- Induction Heating and Welding
- Medical Imaging

Absolute Maximum Ratings (At T <sub>C</sub> = 25°C Unless Otherwise Stated)								
Parameter	Symbol	Conditions	Values	Unit	Note			
Repetitive Peak Reverse Voltage	$V_{RRM}$		1700	٧				
Continuous Forward Current	l <sub>F</sub>	T <sub>C</sub> = 100°C, D = 1	15					
		$T_C = 135^{\circ}C$ , D = 1	10	Α	Fig. 4			
		$T_C = 164^{\circ}C, D = 1$	5					
Non-Repetitive Peak Forward Surge Current, Half Sine Wave	І <sub>Б,ЅМ</sub>	$T_C = 25^{\circ}C$ , $t_P = 10 \text{ ms}$	50	Α				
		$T_C$ = 150°C, $t_P$ = 10 ms	40					
Repetitive Peak Forward Surge Current, Half Sine Wave	I <sub>F,RM</sub>	$T_C = 25^{\circ}\text{C}, t_P = 10 \text{ ms}$		Α				
		$T_C = 150$ °C, $t_P = 10$ ms	21	А				
Non-Repetitive Peak Forward Surge Current	I <sub>F,MAX</sub>	$T_C$ = 25°C, $t_P$ = 10 $\mu$ s	250	Α				
i <sup>2</sup> t Value	∫i²dt	$T_C$ = 25°C, $t_P$ = 10 ms	12	A <sup>2</sup> s				
Non-Repetitive Avalanche Energy	Eas	L = 8 mH, I <sub>AS</sub> = 5 A	100	mJ				
Diode Ruggedness	dV/dt	V <sub>R</sub> = 0 ~ 1360 V	200	V/ns				
Power Dissipation	P <sub>TOT</sub>	T <sub>C</sub> = 25°C	141	W	Fig. 3			
Operating and Storage Temperature	$T_j$ , $T_{stg}$		-55 to 175	°C				



Symbol	Conditions -		Values			Unit	Note
Зуший			Min.	Тур.	Max.	Oilit	Note
V-	I <sub>F</sub> = 5 A, T <sub>j</sub> = 25°C			1.5	1.8	٧	Fig. 1
VF	$I_F = 5 A, T_j = 175^{\circ}C$			2.1			
l <sub>n</sub>	$V_R = 1700 \text{ V, } T_j = 25^{\circ}\text{C}$			1	20	μA	Fig. 2
IR	$V_R = 1700 \text{ V, } T_j = 175^{\circ}\text{C}$			4			
O <sub>o</sub>		$V_{R} = 600 \text{ V}$		28		nС	Fig. 7
Qυ	$\int_{-}^{} I_{F} \leq I_{F,MAX}$ $dI_{F}/dt = 200 A/\mu s$	$V_R = 1200 V$		41		IIC	
t <sub>o</sub>		$V_{R} = 600 \text{ V}$		<b>~</b> 10		ne	
ις		$V_R = 1200 V$		<b>\ 10</b>		115	
C	V <sub>R</sub> = 1 V, f =	= 1MHz		361		nЕ	Fig. 6
	V <sub>R</sub> = 1200 V, f = 1MHz			20		þΓ	
	Symbol  VF  IR  Qc  ts	$ \begin{array}{c} \text{Symbol} & \text{Conditi} \\ \\ V_F & I_F = 5 \text{ A, } T_j \\ I_F = 5 \text{ A, } T_j : \\ \\ I_R & V_R = 1700 \text{ V, } \\ \\ V_R = 1700 \text{ V, } \\ \\ V_R = 1700 \text{ V, } \\ \\ \\ V_R = 100 \text{ A/} \\ \\ \\ V_R = 1 \text{ V, } f = 1 \text$	$\begin{array}{c} \text{Symbol} & \text{Conditions} \\ \\ V_F & I_F = 5 \text{ A, } T_j = 25^{\circ}\text{C} \\ I_F = 5 \text{ A, } T_j = 175^{\circ}\text{C} \\ \\ I_R & V_R = 1700 \text{ V, } T_j = 25^{\circ}\text{C} \\ \\ V_R = 1700 \text{ V, } T_j = 175^{\circ}\text{C} \\ \\ V_R = 1700 \text{ V, } T_j = 175^{\circ}\text{C} \\ \\ V_R = 600 \text{ V} \\ \\ V_R = 1200 \text{ V} \\ \\ $	$\begin{tabular}{c cccc} Symbol & Conditions & \hline & Min. \\ \hline $V_F$ & $I_F=5~A, T_j=25^\circ C$ \\ $I_F=5~A, T_j=175^\circ C$ \\ \hline $I_R$ & $V_R=1700~V, T_j=25^\circ C$ \\ $V_R=1700~V, T_j=175^\circ C$ \\ \hline $Q_C$ & $V_R=1700~V, T_j=175^\circ C$ \\ \hline $Q_C$ & $V_R=600~V$ \\ \hline $I_F\leq I_{F,MAX}$ & $V_R=1200~V$ \\ \hline $d_{IF}/dt=200~A/\mu s$ & $V_R=600~V$ \\ \hline $V_R=1200~V$ \\ \hline $V_R=1200~V$ \\ \hline \end{tabular}$	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$

Thermal/Package Characteristics								
Parameter	Symbol	Conditions	Values			Heit	Note	
		Conditions	Min.	Тур.	Max.	- Unit	Note	
Thermal Resistance, Junction - Case	$R_{thJC}$			1.06		°C/W	Fig. 9	
Weight	W <sub>T</sub>			6.0		g		
Mounting Torque	T <sub>M</sub>	Screws to Heatsink			1.1	Nm		



**Figure 1: Typical Forward Characteristics** 

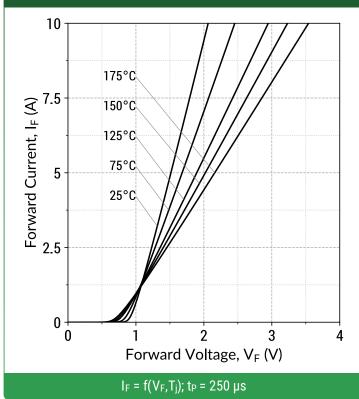
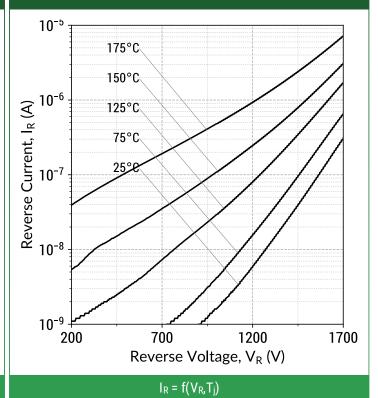
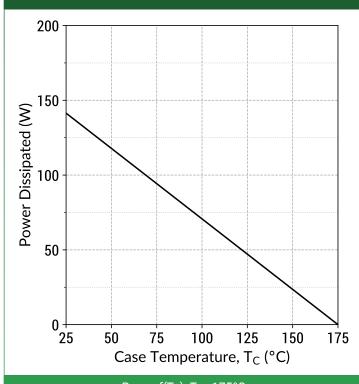


Figure 2: Typical Reverse Characteristics

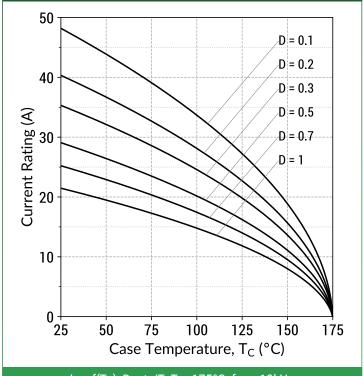


**Figure 3: Power Derating Curves** 



 $P_{TOT} = f(T_C); T_j = 175^{\circ}C$ 

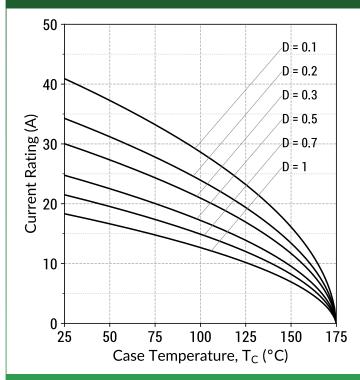
Figure 4: Current Derating Curves (Typical V<sub>F</sub>)



 $I_F = f(T_C)$ ; D =  $t_P/T$ ;  $T_j \le 175$ °C;  $f_{SW} > 10$ kHz

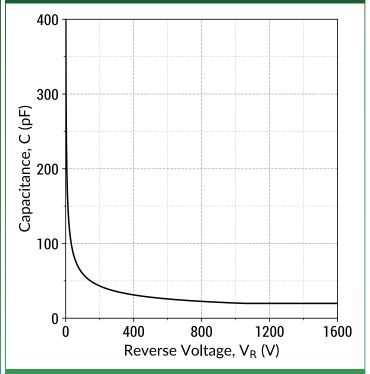


Figure 5: Current Derating Curves (Maximum V<sub>F</sub>)



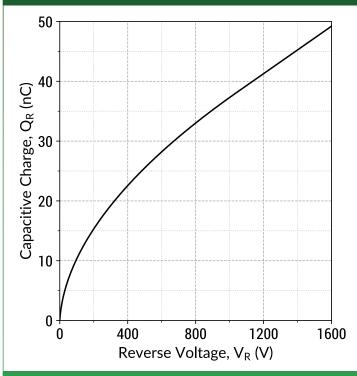
 $I_F = f(T_C); D = t_P/T; T_j \le 175^{\circ}C; f_{SW} > 10kHz$ 

Figure 6: Typical Junction Capacitance vs Reverse Voltage Characteristics



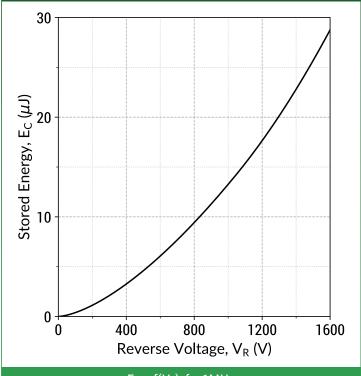
 $C = f(V_R)$ ; f = 1MHz

Figure 7: Typical Capacitive Charge vs Reverse Voltage Characteristics



 $Q_C = f(V_R)$ ; f = 1MHz

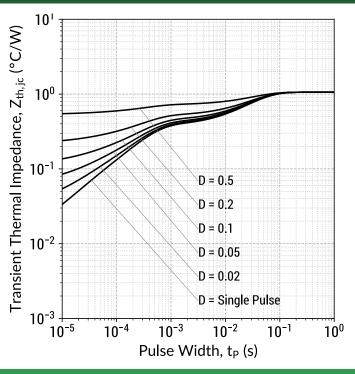
Figure 8: Typical Capacitive Energy vs Reverse Voltage Characteristics



 $E_C = f(V_R)$ ; f = 1MHz

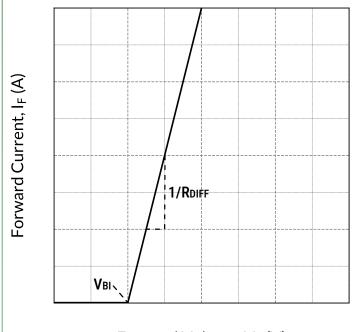


Figure 9: Transient Thermal Impedance



 $Z_{th,jc} = f(t_P,D); D = t_P/T$ 

Figure 10: Forward Curve Model



Forward Voltage,  $V_F(V)$ 

 $I_F = f(V_F, T_j)$ 

### Forward Curve Model Equation:

 $I_F = (V_F - V_{BI})/R_{DIFF} (A)$ 

### Built-In Voltage (V<sub>BI</sub>):

 $V_{BI}(T_j) = m \times T_j + n (V)$  $m = -0.00126 (V/^{\circ}C)$ 

n = 0.997(V)

### Differential Resistance (RDIFF):

 $R_{DIFF}(T_i) = a \times T_i^2 + b \times T_i + c(\Omega)$ 

 $a = 2.04e-06 (\Omega/^{\circ}C^{2})$ 

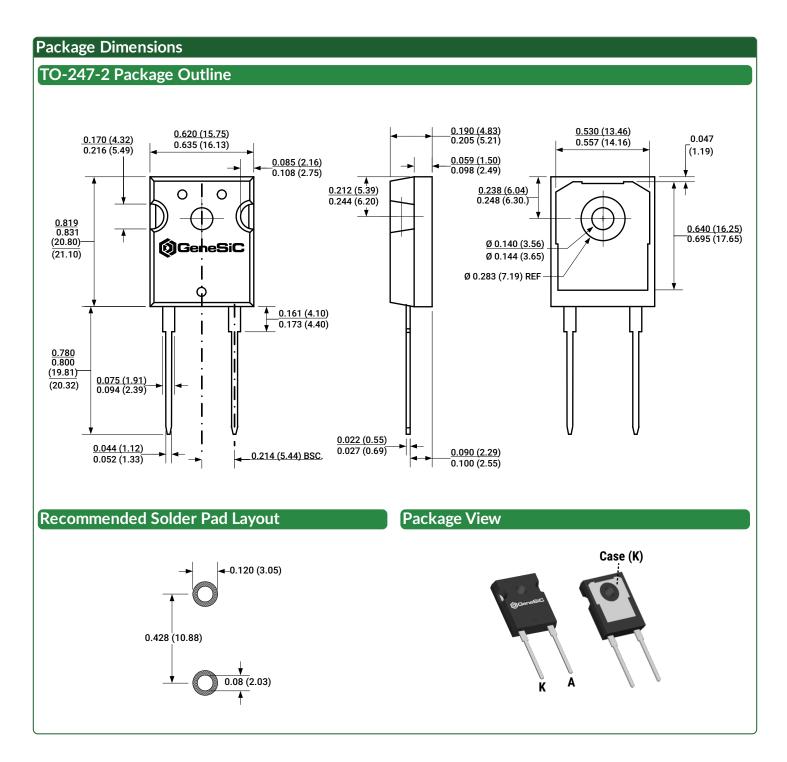
 $b = 0.000704 (\Omega/^{\circ}C)$ 

 $c = 0.0912 (\Omega)$ 

### **Forward Power Loss Equation:**

 $P_{LOSS} = V_{BI}(T_i) \times I_{AVG} + R_{DIFF}(T_i) \times I_{RMS}^2$ 





#### **NOTE**

- 1. CONTROLLED DIMENSION IS INCH. DIMENSION IN BRACKET IS MILLIMETER.
- 2. DIMENSIONS DO NOT INCLUDE END FLASH, MOLD FLASH, MATERIAL PROTRUSIONS.





### Compliance

#### **RoHS Compliance**

The levels of RoHS restricted materials in this product are below the maximum concentration values (also referred to as the threshold limits) permitted for such substances, or are used in an exempted application, in accordance with EU Directive 2011/65/EC (RoHS 2), as adopted by EU member states on January 2, 2013 and amended on March 31, 2015 by EU Directive 2015/863. RoHS Declarations for this product can be obtained from your GeneSiC representative.

#### **REACH Compliance**

REACH substances of high concern (SVHCs) information is available for this product. Since the European Chemical Agency (ECHA) has published notice of their intent to frequently revise the SVHC listing for the foreseeable future, please contact a GeneSiC representative to insure you get the most up-to-date REACH SVHC Declaration. REACH banned substance information (REACH Article 67) is also available upon request.

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#### **Related Links**

SPICE Models: https://www.genesicsemi.com/sic-schottky-mps/GD05MPS17H/GD05MPS17H\_SPICE.zip
 PLECS Models: https://www.genesicsemi.com/sic-schottky-mps/GD05MPS17H/GD05MPS17H\_PLECS.zip
 CAD Models: https://www.genesicsemi.com/sic-schottky-mps/GD05MPS17H/GD05MPS17H\_3D.zip

• Evaluation Boards: https://www.genesicsemi.com/technical-support

Reliability: https://www.genesicsemi.com/reliability
 Compliance: https://www.genesicsemi.com/compliance
 Quality Manual: https://www.genesicsemi.com/quality

#### **Revision History**

Rev 21/Jun: Updated with most recent test data

· Supersedes: Rev 20/Jul



www.genesicsemi.com/sic-schottky-mps/

